Electrode used for producing plasme body, plasma body processing juipment using said dectrode and plasma body processing using said équipment

Publication number: CN1283076 (A) 2001-02-07

Publication date:

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Classification:

Inventor(s):

- International:

H05H1/34; H01J37/32; H05H1/26; H01J37/32; (IPC1-7): H05H1/24;

C23F4/00; H01L21/3065

- European:

H01J37/32D1B

Application number: CN20001021396 20000727

Priority number(s): JP19990212871 19990727; JP19990212872 19990727

Abstract not available for CN 1283076 (A) Abstract of corresponding document: EP 1073091 (A2)

A plasma treatment apparatus comprises plural pairs of electrodes for plasma generation, a treatment chamber for accommodating the electrodes therein, gas supply unit for supplying a plasma-generation gas such as rare gas into the chamber, and a power supply. A pulse-like or AC electric field is applied between the electrodes to generate dielectric barrier discharge plasma of the gas therebetween in the vicinity of atmospheric pressure, so that an object placed between the electrodes is treated by the plasma. At least one of the electrodes is provided with a tubular electrode substrate and a protection layer formed by heat-fusion coating a glass-based material on at least an outer surface exposed to plasma of the tubular electrode substrate. A withstand voltage of the protection layer is within a range of 1 to 50 kV.

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🔁 CN100393182 (C) EP1073091 (A2) DEP1073091 (A3)
DUS6489585 (B1)
TW494709 (B)

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[51] Int. Cl

H05H 1/24

C23F 4/00 H01L 21/3065

[12] 发明专利申请公开说明书

[21] 申请号 00121396.2

[43]公开日 2001年2月7日

[11]公开号 CN 1283076A

[22]申请日 2000.7.27 [21]申请号 00121396.2 [30]优先权

[32]1999.7.27 [33]JP [31]JP11 -212871 [32]1999.7.27 [33]JP [31]JP11 -212872

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权利要求书3 页 说明书23 页 附图页数7 页

[54] 发明名称 用于产生等离子体的电极、使用该电极的 等离子体处理设备以及利用该设备的等 离子体处理

[57]衡要

等离子体处理设备包括用于产生等离子体的多对电极、用于在其中 容纳电极的处理室、用于将例如惰性气体的产生等离子体气体供给室的 气体供给装置和电源。在电极之间施加脉冲或 AC 电压,以便在大气压附 近产生气体的介质阻挡层放电等离子体,从面利用等离子体处理放置在 电极之间的物体。至少一个电极备有管状结构的电极基底和在曝露给电 极基底的等离于体的至少一个表面上的通过热熔涂覆玻璃基材料而形成 的保护层。

